## BAV99 SWITCHING DIODES

## FEATURES

Fast Switching Speed
For General Purpose Switching Applications
High Conductance


Absolute Maximum Ratings ( $\mathrm{T}_{\mathrm{a}}=25^{\circ} \mathrm{C}$ )

| Parameter | Symbol | Value | Unit |
| :---: | :---: | :---: | :---: |
| Repetitive Peak Reverse Voltage | $\mathrm{V}_{\mathrm{RRM}}$ | 85 | V |
| Continuous Reverse Voltage | $\mathrm{V}_{\mathrm{R}}$ | 75 | V |
| Continuous Forward Current (Double Diode Loaded) | $\mathrm{I}_{\mathrm{F}}$ | 125 | mA |
| Continuous Forward Current (Single Diode Loaded) | $\mathrm{I}_{\mathrm{F}}$ | 215 | mA |
| Repetitive Peak Forward Current | $\mathrm{I}_{\mathrm{FRM}}$ | 450 | mA |
| Non-repetitive Peak Forward Surge Current at $=1 \mathrm{~s}$ |  |  |  |
| at $=1 \mathrm{~ms}$ |  |  |  |
| at $=1 \mu \mathrm{~s}$ | $\mathrm{I}_{\mathrm{FSM}}$ | 0.5 | 1 |
| Power Dissipation | $\mathrm{P}_{\text {tot }}$ | 350 | A |
| Junction Temperature | $\mathrm{T}_{\mathrm{j}}$ | 150 | ${ }^{\circ} \mathrm{C}$ |
| Storage Temperature Range | $\mathrm{T}_{\text {stg }}$ | -65 to +150 | ${ }^{\circ} \mathrm{C}$ |

Characteristics at $\mathrm{T}_{\mathrm{a}}=25^{\circ} \mathrm{C}$

| Parameter | Symbol | Max. | Unit |
| :---: | :---: | :---: | :---: |
| $\begin{gathered} \text { Forward Voltage at } \mathrm{I}_{\mathrm{F}}=1 \mathrm{~mA} \\ \text { at } \mathrm{I}_{\mathrm{F}}=10 \mathrm{~mA} \\ \text { at } \mathrm{I}_{\mathrm{F}}=50 \mathrm{~mA} \\ \text { at } \mathrm{I}_{\mathrm{F}}=150 \mathrm{~mA} \\ \hline \end{gathered}$ | $V_{\text {F }}$ | $\begin{gathered} 0.715 \\ 0.855 \\ 1 \\ 1.25 \end{gathered}$ | V |
| $\begin{gathered} \hline \text { Reverse Current at } \mathrm{V}_{\mathrm{R}}=25 \mathrm{~V} \\ \text { at } \mathrm{V}_{R}=75 \mathrm{~V} \\ \text { at } \mathrm{V}_{\mathrm{R}}=25 \mathrm{~V}, \mathrm{~T}_{\mathrm{j}}=150^{\circ} \mathrm{C} \\ \text { at } \mathrm{V}_{\mathrm{R}}=75 \mathrm{~V}, \mathrm{~T}_{\mathrm{j}}=150^{\circ} \mathrm{C} \end{gathered}$ | $I_{\text {R }}$ | $\begin{gathered} 30 \\ 1 \\ 30 \\ 50 \end{gathered}$ | nA <br> $\mu \mathrm{A}$ <br> $\mu \mathrm{A}$ <br> $\mu \mathrm{A}$ |
| Diode Capacitance at $\mathrm{V}_{\mathrm{R}}=0, \mathrm{f}=1 \mathrm{MHz}$ | $\mathrm{C}_{\text {d }}$ | 1.5 | pF |
| Reverse Recovery Time at $\mathrm{I}_{\mathrm{F}}=\mathrm{I}_{\mathrm{R}}=10 \mathrm{~mA}, \mathrm{I}_{\mathrm{R}}=1 \mathrm{~mA}, \mathrm{R}_{\mathrm{L}}=100 \Omega$ | $\mathrm{t}_{\text {IT }}$ | 4 | ns |

Typical Characteristics


Figure 1. Reverse Voltage vs Reverse Current BV - 1.0 to 100 uA


Figure 3. Forward Voltage vs Forward Current VF - 1.0 to 100 uA


Figure 5. Forward Voltage vs Forward Current VF - $10-800 \mathrm{~mA}$


Figure 7. Reverse Recovery Time vs Reverse Current TRR - IR 10 mA vs $\mathbf{6 0} \mathrm{mA}$

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Figure 2. Reverse Current vs Reverse Voltage IR - 10 to 100 V


Figure 4. Forward Voltage vs Forward Current VF - 0.1 to 10 mA


Figure 6. Total Capacitance vs Reverse Voltage


Figure 8. Average Rectified Current ( $\mathrm{I}_{\text {F(AV) }}$ ) versus Ambient Temperature ( $\mathrm{T}_{\mathrm{A}}$ )

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